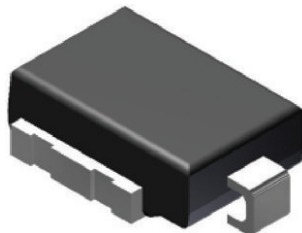


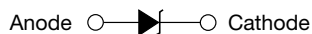


Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



DO-218 Compatible



PRIMARY CHARACTERISTICS	
V_{WM}	10 V to 43 V
V_{BR}	11.1 V to 52.8 V
P_{PPM} (10 x 1000 μ s)	4600 W
P_{PPM} (10 x 10 000 μ s)	3600 W
P_D	6 W
I_{FSM}	600 A
T_J max.	175 °C
Polarity	Unidirectional
Package	DO-218AC

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- $T_J = 175$ °C capability suitable for high reliability and automotive requirement
- Available in unidirectional polarity only
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating
Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)			
PARAMETER	SYMBOL	VALUE	UNIT
Peak pulse power dissipation	P_{PPM}	with 10/1000 μ s waveform	4600
		with 10/10 000 μ s waveform	3600
Power dissipation on infinite heatsink at $T_C = 25$ °C (fig. 1)	P_D	6.0	W
Peak pulse current with 10/1000 μ s waveform	I_{PPM} ⁽¹⁾	See next table	A
Peak forward surge current 8.3 ms single half sine-wave	I_{FSM}	600	A
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +175	°C

Note

⁽¹⁾ Non-repetitive current pulse at $T_A = 25$ °C



SM6S10AT thru SM6S43AT

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)										
DEVICE TYPE	BREAKDOWN VOLTAGE V_{BR} (V)			TEST CURRENT I_T (mA)	STAND-OFF VOLTAGE V_{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V_{WM} I_D (μA)	MAXIMUM REVERSE LEAKAGE AT V_{WM} $T_J = 175\text{ }^\circ\text{C}$ I_D (μA)	MAX. PEAK PULSE CURRENT AT 10/1000 μs WAVEFORM (A)	MAXIMUM CLAMPING VOLTAGE AT I_{PPM} V_C (V)	TYPICAL TEMP. COEFFICIENT OF V_{BR} α_T ($\%/^\circ\text{C}$)
	MIN.	NOM.	MAX.							
SM6S10AT	11.1	11.7	12.3	5.0	10.0	15	250	271	17.0	0.069
SM6S11AT	12.2	12.9	13.5	5.0	11.0	10	150	253	18.2	0.072
SM6S12AT	13.3	14.0	14.7	5.0	12.0	10	150	231	19.9	0.074
SM6S13AT	14.4	15.2	15.9	5.0	13.0	10	150	214	21.5	0.076
SM6S14AT	15.6	16.4	17.2	5.0	14.0	10	150	198	23.2	0.078
SM6S15AT	16.7	17.6	18.5	5.0	15.0	10	150	189	24.4	0.080
SM6S16AT	17.8	18.8	19.7	5.0	16.0	10	150	177	26.0	0.081
SM6S17AT	18.9	19.9	20.9	5.0	17.0	10	150	167	27.6	0.082
SM6S18AT	20.0	21.1	22.1	5.0	18.0	10	150	158	29.2	0.083
SM6S20AT	22.2	23.4	24.5	5.0	20.0	10	150	142	32.4	0.085
SM6S22AT	24.4	25.7	26.9	5.0	22.0	10	150	130	35.5	0.086
SM6S24AT	26.7	28.1	29.5	5.0	24.0	10	150	118	38.9	0.087
SM6S26AT	28.9	30.4	31.9	5.0	26.0	10	150	109	42.1	0.088
SM6S28AT	31.1	32.8	34.4	5.0	28.0	10	150	101	45.4	0.089
SM6S30AT	33.3	35.1	36.8	5.0	30.0	10	150	95	48.4	0.090
SM6S33AT	36.7	38.7	40.6	5.0	33.0	10	150	86	53.3	0.091
SM6S36AT	40.0	42.1	44.2	5.0	36.0	10	150	79	58.1	0.091
SM6S40AT	44.4	46.8	49.1	5.0	40.0	10	150	71	64.5	0.092
SM6S43AT	47.8	50.3	52.8	5.0	43.0	10	150	66	69.4	0.093

Notes

- For all types maximum $V_F = 1.9\text{ V}$ at $I_F = 100\text{ A}$ measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum
- (1) To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at $T_J = V_{BR}$ at $25\text{ }^\circ\text{C} \times (1 + \alpha_T \times (T_J - 25))$

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VALUE	UNIT
Typical thermal resistance, junction to case	$R_{\theta JC}$	0.95	$^\circ\text{C/W}$

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SM6S10ATHE3/I (1)	2.550	I	750	13" diameter plastic tape and reel, anode towards the sprocket hole

Note

- (1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

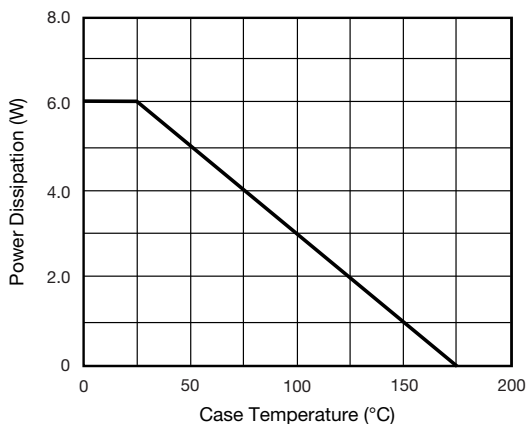


Fig. 1 - Power Derating Curve

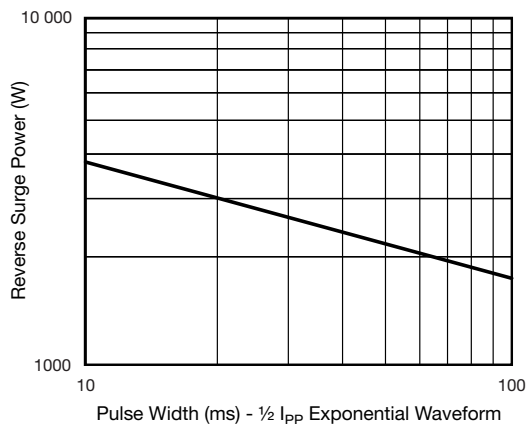


Fig. 4 - Reverse Power Capability

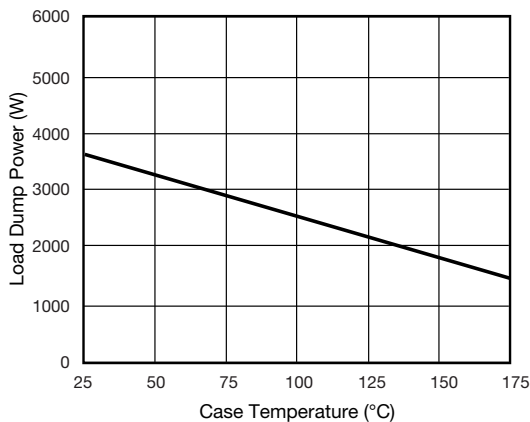


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

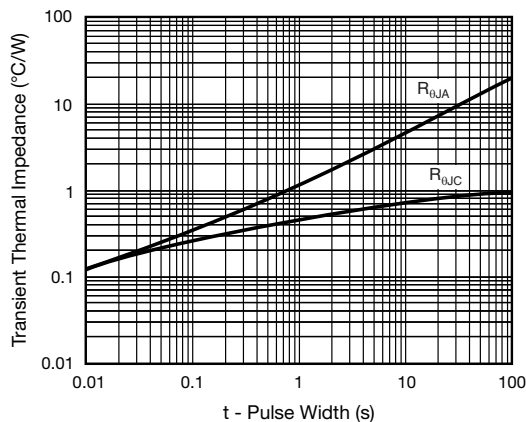


Fig. 5 - Typical Transient Thermal Impedance

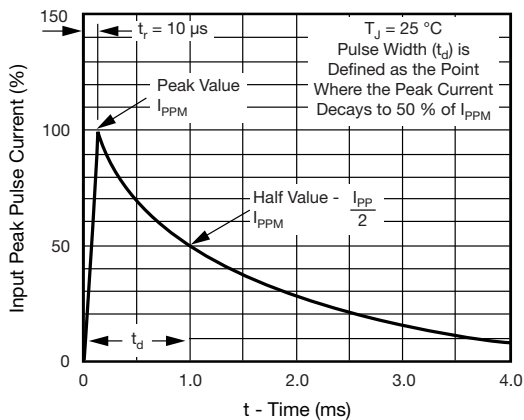
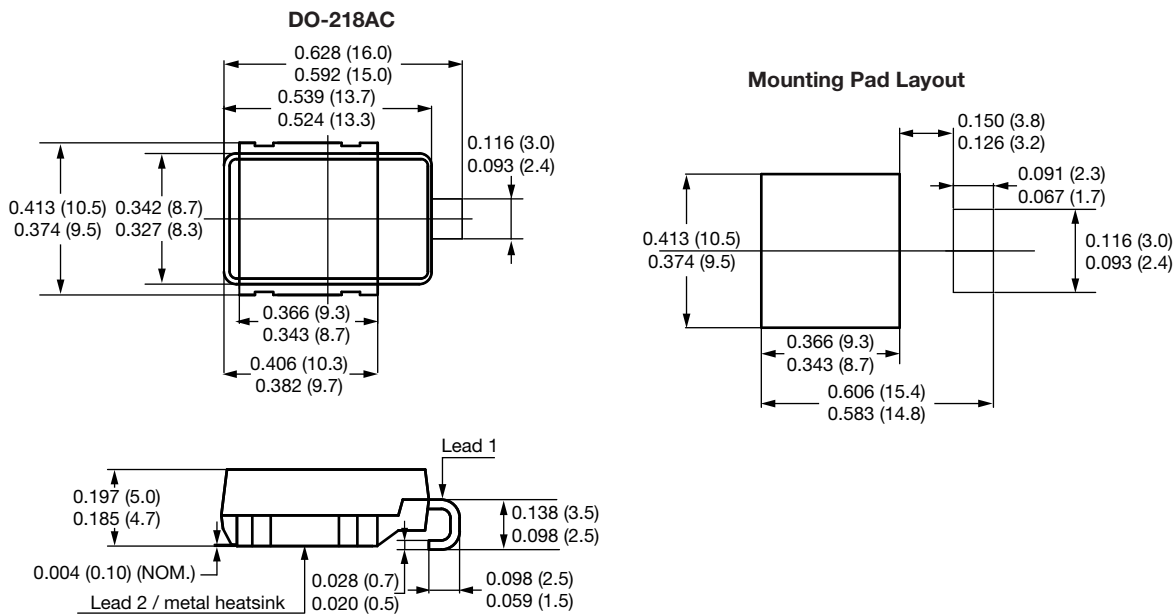


Fig. 3 - Pulse Waveform



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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